



DMP6110SVT

#### P-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C
	105m $\Omega$ @ V <sub>GS</sub> = -10V	-7.3A
-60V	130mΩ @ V <sub>GS</sub> = -4.5V	-6.5A

# **Description and Applications**

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$  and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

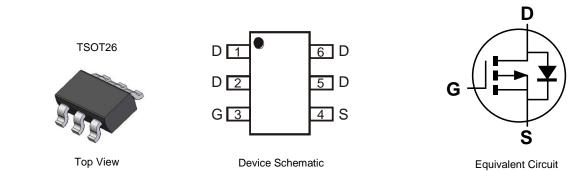
- Backlighting
- Power Management Functions
- DC-DC Converters

# Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: TSOT26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.008 grams (Approximate)



#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMP6110SVT-7	TSOT26	3,000/Tape & Reel
DMP6110SVT-13	TSOT26	10,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**

Notes:

		$\Box$	
	I	P61	MΥ
Т			

 $\begin{array}{l} {\sf P61} = \underline{P} {\sf roduct} \ {\sf Type} \ {\sf Marking} \ {\sf Code} \\ {\sf YM} \ \underline{or} \ {\sf YM} = {\sf Date} \ {\sf Code} \ {\sf Marking} \\ {\sf Y} \ or \ {\sf Y} = {\sf Year} \ (ex: \ {\sf C} = 2015) \\ {\sf M} = {\sf Month} \ (ex: \ {\sf 9} = {\sf September}) \end{array}$ 

Date Code Key												
Year	201	5	2016		2017	20	18	2019		2020		2021
Code	С		D		E		F	G		Н		
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



#### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage	V <sub>DSS</sub>	-60	V	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 6) $V_{GS}$ = -10V	T <sub>C</sub> = +25°C T <sub>C</sub> = +70°C	۱ <sub>D</sub>	-7.3 -5.8	A
Maximum Body Diode Forward Current (Note 6)		ls	-1.8	А
Pulsed Drain Current (380µs Pulse, 1% Duty Cycle)	I <sub>DM</sub>	-24	А	
Avalanche Current (Note 7) L = 0.1mH	I <sub>AS</sub>	-19	А	
Repetitive Avalanche Energy (Note 7) L = 0.1mH		E <sub>AS</sub>	18	mJ

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	D	1.2	W
Total Fower Dissipation (Note 5)	$T_A = +70^{\circ}C$	PD	0.75	
Thermal Resistance, Junction to Ambient (Note 5)	Steady state	Р	105	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{ heta JA}$	60	°C/W
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$	Pn	1.8	W
Total Fower Dissipation (Note 0)	T <sub>A</sub> = +70°C	PD	1.1	
Thermal Resistance, Junction to Ambient (Note 6)	Steady state	P	69	°C/W
Thermal Resistance, Junction to Ambient (Note 0)	t<10s	$R_{ heta}$ JA	39	°C/W
Thermal Resistance, Junction to Case (Note 6)		$R_{ ext{ heta}JC}$	15	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

	- · · ·		_			
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)			1	1	1	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-60	—		V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	IDSS	_		-1	μA	$V_{DS} = -48V, V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>			100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-1		-3	V	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$
Static Drain-Source On-Resistance			—	105	mΩ	$V_{GS} = -10V, I_D = -4.5A$
	R <sub>DS(ON)</sub>	_		130	11152	$V_{GS} = -4.5V, I_D = -3.5A$
Diode Forward Voltage	V <sub>SD</sub>	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C <sub>iss</sub>		969			$V_{DS}$ = -30V, $V_{GS}$ = 0V, f = 1.0MHz
Output Capacitance	Coss		57		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	44	—		
Gate Resistance	R <sub>G</sub>	_	13.7	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	_	8.2	_		
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	_	17.2	_	nC	V 20V L 424
Gate-Source Charge	Q <sub>gs</sub>	_	3.0	_	nc	$V_{DS} = -30V, I_D = -12A$
Gate-Drain Charge	Q <sub>gd</sub>	_	3.1	_		
Turn-On Delay Time	t <sub>D(ON)</sub>		4.4			
Turn-On Rise Time	t <sub>R</sub>		23			$V_{GS} = -10V, V_{DS} = -30V, R_{GEN} = 3\Omega,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>		34		ns	I <sub>D</sub> = -12A
Turn-Off Fall Time	tF		42	_		
Body Diode Reverse Recovery Time	t <sub>RR</sub>		13.2	_	ns	1 120 dl/dt 1000/up
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>		6.18		nC	-I <sub>S</sub> = -12A, dI/dt = 100A/μs

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

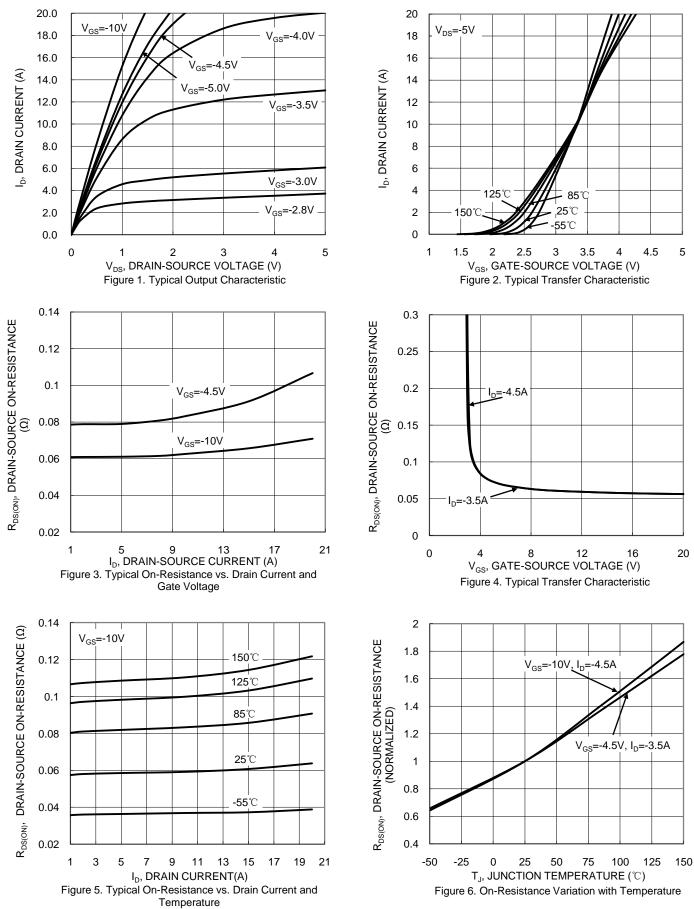
7.  $I_{AS}$  and  $E_{AS}$  rating are based on low frequency and duty cycles to keep  $T_{J}$  = +25°C.

8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.



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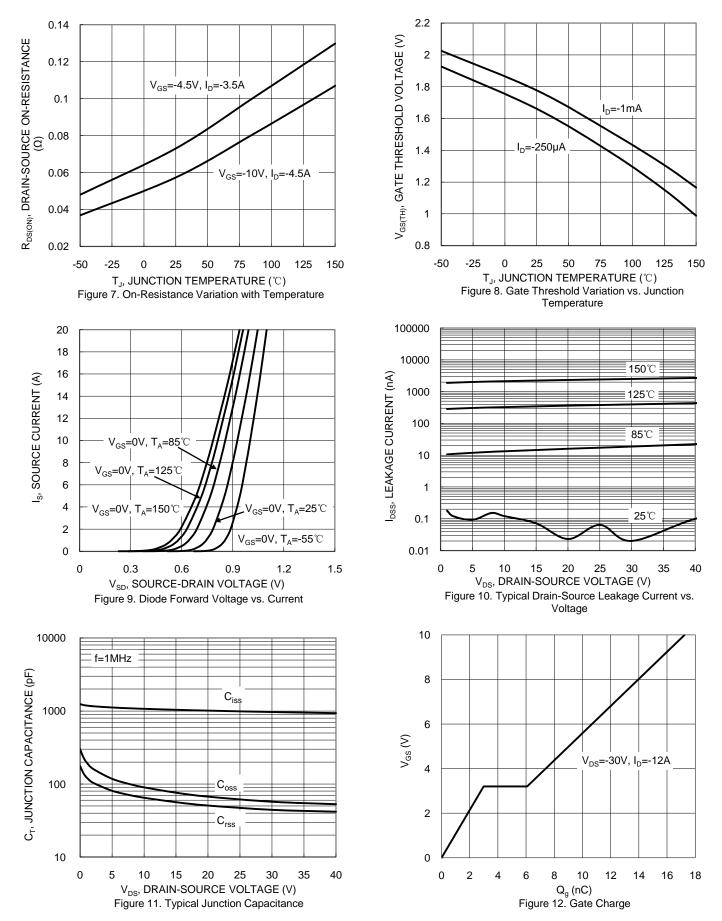
NEW PRODUCT

DMP6110SVT Document number: DS37594 Rev. 2 - 2



NEW PRODUCT

## DMP6110SVT

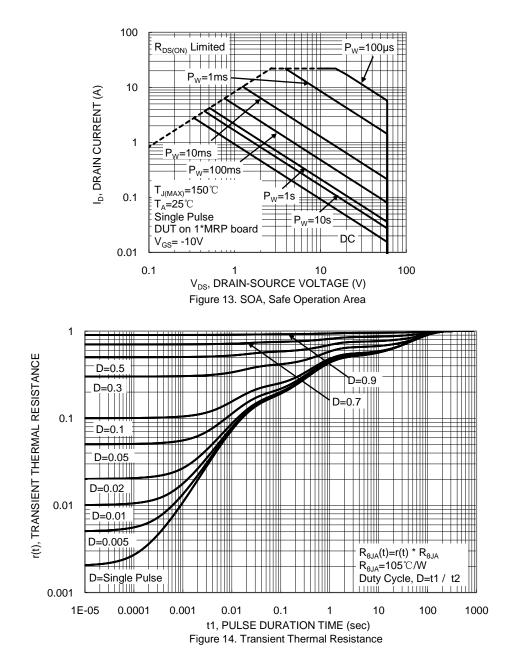


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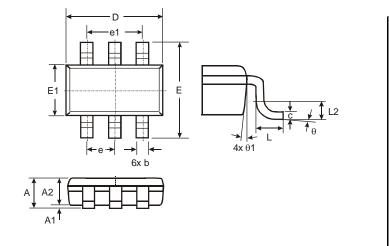






# **Package Outline Dimensions**

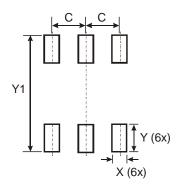
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



TSOT26							
Dim	Min	Max	Тур				
Α	-	1.00	-				
A1	0.01	0.10	-				
A2	0.84	0.90	-				
D	-	-	2.90				
Е	-	-	2.80				
E1	-	1	1.60				
b	0.30	0.45	-				
С	0.12	0.20	-				
е	-	-	0.95				
e1	-	-	1.90				
L	0.30	0.50					
L2	-	-	0.25				
θ	0°	8°	4°				
θ1	4°	12°	—				
All D	All Dimensions in mm						

## Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	0.950
Х	0.700
Y	1.000
Y1	3.199



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